

**Green Products** 

# 15SQ SERIES SCHOTTKY BARRIER RECTIFIER

### **Applications:**

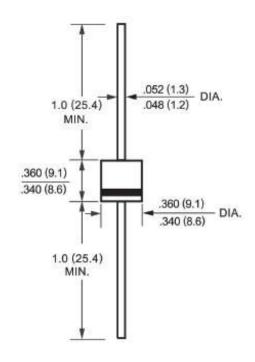
- DC-DC converters
- AC adapter
- · High frequency rectification circuit
- Bypass diodes
- Photovoltaic Solar cell Protection Schottky Rectifier

#### Features:

- Super-high speed & low noise switching
- Low voltage drop
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



#### Mechanical Dimensions: In Inches/ mm



**R-6** 

<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •





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#### **Marking Diagram:**



Where XXX is 030/045/050/060/100 Where XXXXX is YYWWL

15 = Forward Current (15A)

S = Package Type Q = Device Type

XXX = Reverse Voltage (30/45/50/60/100V)

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping	
15SQ030			
15SQ045	D.G.		
15SQ050	R-6	500pcs / reel	
15SQ060	(Pb-Free)	•	
15SQ100			

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## **Maximum Rating:**

Characteristics	Symbol	Conditions	Value		Unit
		-	15SQ030	30	
Peak Repetitive Reverse Voltage	$V_{RRM}$		15SQ045	45	
Working Peak Reverse Voltage	$V_{RWM}$		15SQ050	50	V
DC Blocking Voltage	$V_R$		15SQ060	60	
			15SQ100	100	
Average Rectified Forward Current	I <sub>F(AV)</sub>	R- load, Ta=50℃	15		Α
Surge(Non-repetitive)			15SQ030		
Forward Current			15SQ045	300	
	I <sub>FSM</sub>	8.3ms single half sine-wave	15SQ050	300	Α
			15SQ060		
			15SQ100	340	

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## Electrical Characteristics (Ta=25℃ Unless otherwise specified)

Characteristics	Symbol	Conditions			Тур.	Max.	Unit
Peak Forward Voltage*		I <sub>FM</sub> =15.0А,Та=25°С		15SQ030	0.48	0.55	
				15SQ045	0.48	0.55	
	VFM			15SQ050	0.58	0.68	V
			15SQ060	0.58	0.68	]	
				15SQ100	0.78	0.83	]
Peak Reverse Current*	IRRM1	V <sub>RM</sub> =V <sub>RRM</sub>	Ta=25℃	-	-	0.5	
	IRRM2		Ta=100℃	-	-	25	
Thermal Resistance	R өJ-с	Between junction and case		-	3.0	-	°C/W
	R өJ-L	Between jun	ction and lead	-	2.0	-	C/VV

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

## **Thermal-Mechanical Specifications:**

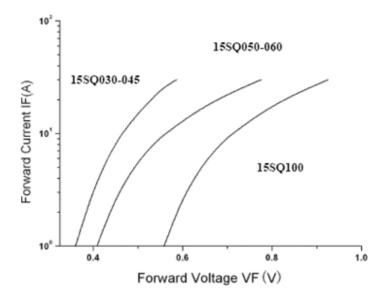
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature at reduced reverse voltage at reduced reverse voltage in DC forward mode	TJ	$V_{R}{\leqslant}80\%V_{RRM} \ V_{R}{\leqslant}50\%V_{RRM}$	-55 to +150 -55 to +180 -55 to +200	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Approximate Weight	wt	-	2.24	g
Case Style		R-6		

<sup>•</sup> China - Germany - Korea - Singapore - United States •

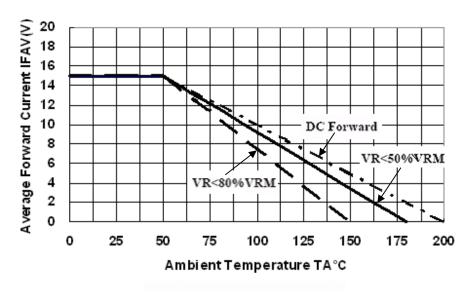
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**Typical Forward Characteristics** 



## **Current Derating**

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